





Fig.2:

The wide dynamic range provides for 70dB at 10.7 MHz, and still gives 58dB at 21.4 MHz, with an error of  $\pm 1$  dB.

The two integrated circuits from Signetics-Philips, NE 604 AN and NE 605 AN, are even designed for 85dB dynamics with an error of  $\pm 2$  dB. Unfortunately, the wiring required is more expensive, since an additional intermediate-frequency filter is needed.

The signal is passed on to pin-7 of the MC 3356P. For correct operation, the input voltage range lies between  $30\mu\text{V}$  (-77dBm) and  $80\text{mV}$  (-1dBm), measured at pin-20. From pin-14, the output signal goes through a voltage divider and a pre-resistance and arrives at the indicator. With the given circuit, a range of 50dB can be displayed linearly on an indicator with a full-scale reading of  $100\mu\text{A}$ . The gradient is thus  $2\mu\text{A}/\text{dB}$  (Fig.2).

## 2. DESCRIPTION OF CIRCUIT

The circuit shown here with the MC 3356P operates in the broad band, from approximately 5 MHz to 22 MHz. Only the input circuit of the pre-amplifier has to be in resonance with the intermediate frequency.

The intermediate-frequency signal is transmitted from the crystal filter of the adjuster to the MOS-FET pre-amplifier (Fig.1). The latter has to amplify the signal and simultaneously minimise the load of the crystal filter. The drain oscillation circuit is tuned to the intermediate frequency in use.

## 3. PRE-TUNING

1. An intermediate-frequency signal is fed in to pin-7 at -70dBm. The indicator is set precisely to  $0\mu\text{A}$  using potentiometer P2.
2. Raise the signal level to -20dBm and tune the indicator deflection to  $100\mu\text{A}$  (full-scale reading). The linearity is controlled by reducing the signal in 10dB stages.

Should it not be possible to calibrate, P1 can be replaced by an  $8.2\text{k}\Omega$  resistor.



#### 4.

## INSTRUCTIONS FOR ASSEMBLY

- ① The completed circuit should be pre-tuned and tested for correct operation before assembly, together with the indicator, using a standard signal generator and a reducer (corresponding to 3).
- ② The signal for the S-meter is drawn off after the SSB crystal filter. To keep the additional capacity load low, a UHF-FET with a small Cg1S should be used.
- ③ The MOS-FET amplifier should be mounted in close proximity to the crystal filter. Using the SMD technique for assembly is advantageous. The remaining part of the circuit is placed in a free corner of the equipment and connected by means of thin coaxial cable.
- ④ No AGC stages should be present between the RX input and the S-meter. Should there be an AGC, disconnect it and replace it by fixed voltages.
- ⑤ The display range of the S-meter incorporated into the RX is dependent on the amplification of the equipment between the aerial socket and the crystal filter output.

Examples of MOS-FET stages:

AGC prior to G1; now connect G1 at 0 V DC.

AGC prior to G2; now connect G2 (DC), at about 4 V higher than the voltage connected to the source (measured against the earth).

#### 5.

## FINAL TUNING

- ① The built-in S-meter is now adjusted to the equipment. The output circuit of the S-meter pre-amplifier is tuned to the maximum reading by means of a test signal at the receiver input.
- ② Now increase the input signal in 10 dB stages until the indicator registers 100 micro-A as precisely as possible. Set the pointer to full-scale reading (100 micro-A) using P2. The linearity is checked by reducing the input signal. Finally the equipment is marked with an appropriate scale.
- ③ Example: a signal of -80dBm gives, e.g., 96 $\mu$ A. So this is corrected to 100 $\mu$ A using P2. Thus we can obtain: 100 $\mu$ A = -80dBm, 80 $\mu$ A = -90dBm, 60 $\mu$ A = -100dBm.

## 6. LITERATURE

- (1) Specification sheet MC 3356 from Motorola
- (2) Specification sheet NE 604 / NE 605 from Signetics / Philips